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MADE EASY ELECTRONICS ENGINEERING

Material Science By-Rohit Tripathi Sir

- Theory
- Explanation
- Derivation
- Example
- Shortcuts
- Previous Years Question With Solution

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CRYSTAL STRUCTURE

- 1) Atomic Arrangement in Solids.
- 2) Cubic Crystal System.
- 3) Miller Indices.
- 4) Bravais crystal structure.
- s) Structural Imperfections.

* ATOMIC ARRANGEMENT IN SOLIDS ..

CRYSTAL! It is a Solid material in which Atomic or molecular

sarrangement is leviodic

*This Property of Crystal is known as CRYSTALLINITY.

SINGLE CRYSTAL MATERIAL ..

*If material is having only one type of Periodical Arrangement then material is carried single crystal.

* These materials are ANISOTROPIC MATERIALS. For Eg QUARTZ.

POLYCRYSTALLINE MATERIAL:

* These materials are divided into no. of small regions. These

regions are called GRAINS. *within each grain atomic or molecular arrangement is PERIODIC but this arrangement varies from one grain to

- Property depends on direction. the other. FOR EG POLYCRYSTALLINE SILICON.

*These materials are Isdiopic materials.

Note: (Aniso lãopic & Dsolãopic material):-

ANISOTROPIC MATERIAL ..

A material is called ANISOTROPIC if properties of material depends on the direction in which they are measured.

ISOTROPIC MATERIAL!

* * A material is called ISOTROPIC if properties of material are direction Independent.

*AMORPHOUS MATERIAL:	•
SiO2 (gas)	
Slow cooling Exliemely fast coding	
ANNEALING. Supercooling	
* soud	
Quartz Glass	
(crystalline (Amorphous	
material) material)	
* when Atoms or molecules are not given oppurtunity to	6
arrange in regular or periodic manner, an Antorphous	85
anarge in equal be formed.	
MATERIAL may be formed. Known on GLASS.	•
For Eg: Supercooled state of SiO2 is known as GLASS. (AMORPHOUS MATERIAL)	
	0
*whereas on ANNEALING, SiO2 may crystallize risto QUARTZ. (CRYSTALLINE MATERIAL).	0
MATERIAL).	
he extremely long and	6
of ther cases, molecules may be extremely long and irregular in shape so that periodical arrangement may not be obtained as in the case of POLYMERS.	
irregular in snape so the case of POLYMERS.	•
not be objectives	
EPITAXIAL PROCESS:	
substrate is known as EPITAXIAL PROCESS. substrate is known as EPITAXIAL PROCESS.	
1) by a Si Crystal, arrangement of atoons repeals person-	
substrate is whoman substrate is atoms repeals periodi- i) In a Si Crystal, arrangement of atoms repeals periodi- carry. This material can be classified on:	(
1 + Li Lavia 1 & TTO 100 PI 1000	(
b) Polycrystalline & Armosphous (material cenit be both).	(
d Single Unisland + "	
d) Epitaxial & Single Crystal.	(Class

CRYSTAL SYSTEM!

1) UNIT CELL !-

*It is defined as the minimum Area (ell in Two dimension of the minimum volume (ell in 3-dimension, by repeatition of which a Crystal may be formed.

2) PARAMETERS OF UNIT CELL'S.

- a) CELL DIMENSION
- b) Angle between axis
- c) no et atorns per unit cell.
- d) co-ordination number.
- e) Atomic Packing factor (APF).

Mathematically:

APF = No of atoms per unit (eux atomic Vol. Vol. of unit (eu.

* (o-ordination number:

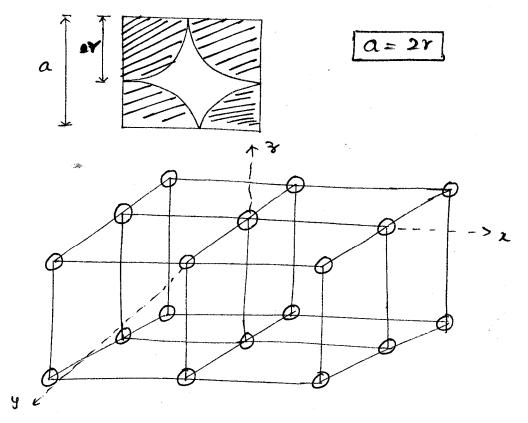
*Ine no of atoms which are in physical Contact with a pouticular atoms in a crystal structure, is known as co-ordi-NATION NUMBER:-

* CUBIC CRYSTAL SYSTEM !.

) SIMPLE CUBIC!

* In Simple Cubic there are 8 Corner atoms.

* Atoms are in Physical contact along EDGE of the Cube.



No of atoms per unit cell= 8 x 1 =1

$$APf = \frac{1 \times \frac{4}{3} \text{ Th}^3}{a^3} = 0.52 ; \quad a = 2r.$$

co-ordination number = 6. = a atoms in contact in each direction.

* Fox Eg:

- i) Manganese
- ii) Flourspar etc.

) Body (entered cubic (BCC):-

- * In Bic there are 8 corner atoms and I Body centered atom.
- : Atoms are in Physical contact along Body diagonal.